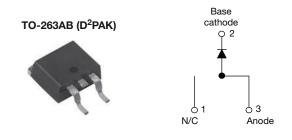
VS-6TQ035SPbF, VS-6TQ040SPbF, VS-6TQ045SPbF



**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 6 A



PRODUCT SUMMARY							
Package	TO-263AB (D <sup>2</sup> PAK)						
I <sub>F(AV)</sub>	6 A						
V <sub>R</sub>	35 V, 40 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.53 V						
I <sub>RM</sub>	7 mA at 125 °C						
T <sub>J</sub> max.	175 °C						
Diode variation	Single die						
E <sub>AS</sub>	8 mJ						

### FEATURES

- 175 °C T<sub>J</sub> operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES								
I <sub>F(AV)</sub>	Rectangular waveform	6	А						
V <sub>RRM</sub>	Range	35 to 45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	690	А						
V <sub>F</sub>	6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.53	V						
TJ	Range	-55 to +175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6TQ035SPbF	VS-6TQ040SPbF	VS-6TQ045SPbF	UNITS				
Maximum DC reverse voltage	V <sub>R</sub>	35	40	45	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>		40	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 164$ °C	6						
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	690	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	140						
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11.	8	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by $T_J$ maximum	1.20	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		6 A	T <sub>1</sub> = 25 °C	0.60					
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	12 A	1j=25 C	0.73	v				
	VFM (**	6 A	T <sub>1</sub> = 125 °C	0.53					
		12 A	$1_{\rm J} = 125$ C	0.64	1				
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V - Poted V	0.8	mA				
See fig. 2	IRM ( ''	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7					
Threshold voltage	V <sub>F(TO)</sub>	T T mavimum		0.35	V				
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		18.23	mΩ				
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	400	pF					
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs				

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4		°044			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W			
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque maximum				12 (10)	(lbf · in)			
Marking device				6TQ035S				
			Case style D <sup>2</sup> PAK	6TQ040S				
				6TQ045S				



### VS-6TQ035SPbF, VS-6TQ040SPbF, VS-6TQ045SPbF

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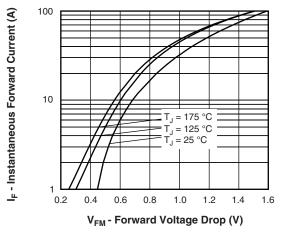


Fig. 1 - Maximum Forward Voltage Drop Characteristics

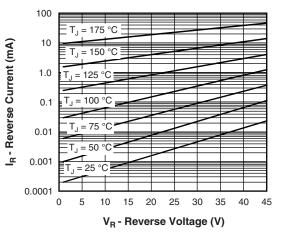


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

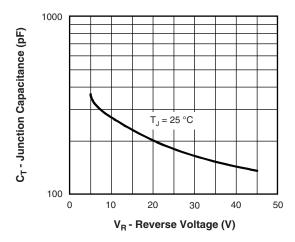
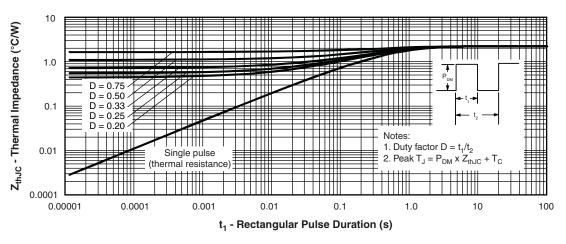
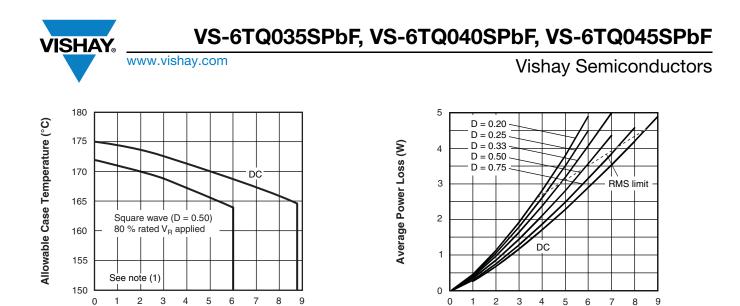


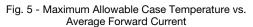
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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IF(AV) - Average Forward Current (A)



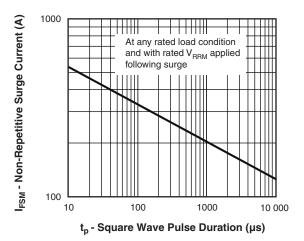


Fig. 7 - Maximum Non-Repetitive Surge Current

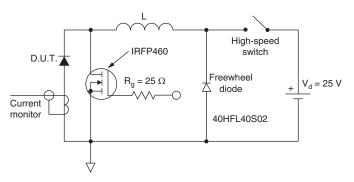


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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## VS-6TQ035SPbF, VS-6TQ040SPbF, VS-6TQ045SPbF

**Vishay Semiconductors** 

### **ORDERING INFORMATION TABLE**

Device code	VS-	6	т	Q	045	S	TRL	PbF	
		2	3	4	5	6	7	8	
	1 2 3								
	4 5 6	- Vol	ottky "C tage rati D <sup>2</sup> PAK	040 =	= 35 V = 40 V = 45 V				
	7	• N	<ul> <li>None = tube (50 pieces)</li> <li>TRL = tape and reel (left oriented)</li> </ul>						
	8		RR = ta <sub>l</sub> <sup>=</sup> = lead	ed)					

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER REEL	QUANTITY PER REEL MINIMUM ORDER QUANTITY								
VS-6TQ035SPBF	50	1000	Antistatic plastic tubes							
VS-6TQ035STRRPBF	800	800	13" diameter plastic tape and reel							
VS-6TQ035STRLPBF	800	800	13" diameter plastic tape and reel							
VS-6TQ040SPBF	50	1000	Antistatic plastic tubes							
VS-6TQ040STRRPBF	800	800	13" diameter plastic tape and reel							
VS-6TQ040STRLPBF	800	800	13" diameter plastic tape and reel							
VS-6TQ045SPBF	50	1000	Antistatic plastic tubes							
VS-6TQ045STRRPBF	800	800	13" diameter plastic tape and reel							
VS-6TQ045STRLPBF	800	800	13" diameter plastic tape and reel							

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

## **Outline Dimensions**



D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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SHA



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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